

P-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$			
- 60	0.0093 at V _{GS} = - 10 V	- 90		
- 60	0.0118 at V _{GS} = - 4.5 V	- 90		

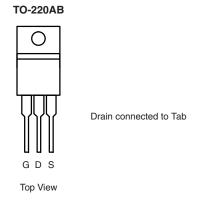
FEATURES

- TrenchFET® Power MOSFET
- Compliant to RoHS Directive 2002/95/EC

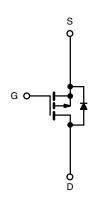


APPLICATIONS

• DC/DC Primary Switch



Ordering Information: SUP90P06-09L-E3 (Lead (Pb)-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	- 60	V	
Gate-Source Voltage	V _{GS}	± 20] v		
Continuous Dusin Comment /T 175 9000	T _C = 25 °C	l _D	- 90	Δ.	
Continuous Drain Current (T _J = 175 °C) ^C	T _C = 125 °C		- 67		
Pulsed Drain Current	I _{DM}	- 200	A		
Avalanche Current	L = 0.1 mH	I _{AS}	- 65		
Single Pulse Avalanche Energy ^a	L = 0.1 IIII	E _{AS}	211	mJ	
Power Dissipation	T _C = 25 °C	P _D 250 ^b		W	
rower Dissipation	T _A = 25 °C	' D	2.4	٧٧	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 175	°C		

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Limit	Unit	
Junction-to-Ambient Free Air	R _{thJA}	62	°C/W	
Junction-to-Case	R _{thJC}	0.6	C/VV	

Notes:

- a. Duty cycle \leq 1 %.
- b. See SOA curve for voltage derating.
- c. Limited by package.

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SPECIFICATIONS (T _J = 25				_			
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	1						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V, } I_D = -250 \mu\text{A}$	- 60			٧	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1		- 3		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
		V _{DS} = - 60 V, V _{GS} = 0 V			- 1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125 \text{ °C}$			- 50	μΑ	
		V _{DS} = - 60 V, V _{GS} = 0 V, T _J = 175 °C			- 250		
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	- 120			Α	
		V _{GS} = - 10 V, I _D = - 30 A		0.0074	0.0093		
		V _{GS} = - 10 V, I _D = - 30 A, T _J = 125 °C			0.0150		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -10 \text{ V}, I_D = -30 \text{ A}, T_J = 175 ^{\circ}\text{C}$			0.0190	Ω	
		V _{GS} = - 4.5 V, I _D = - 20 A		0.0094	0.0118		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 30 A	20			S	
Dynamic ^b	•			•			
Input Capacitance	C _{iss}			9200		pF	
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = - 25 V, f = 1 MHz		975			
Reverse Transfer Capacitance	C _{rss}	1		760			
Total Gate Charge ^c	Q_g			160	240		
Gate-Source Charge ^c	Q _{gs}	V _{DS} = - 30 V, V _{GS} = - 10 V, I _D = - 90 A		40		nC	
Gate-Drain Charge ^c	Q _{gd}	1		36			
Gate Resistance	R _g	f = 1.0 MHz		3		Ω	
Turn-On Delay Time ^c	t _{d(on)}			20	30		
Rise Time ^c	t _r	$V_{DD} = -30 \text{ V}, R_{L} = 0.33 \Omega$		190	285	1	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong$ - 90 A, V_{GEN} = - 10 V, R_g = 2.5 Ω		140	210	ns	
Fall Time ^c	t _f	1		300	450		
Source-Drain Diode Ratings and Characteristics (T _C = 25 °C) ^b							
Continuous Current	I _S				- 90	_	
Pulsed Current	I _{SM}	М			- 200	Α	
Forward Voltage ^a	V _{SD}	I _F = - 50 A, V _{GS} = 0 V		- 1.0	- 1.5	V	
Reverse Recovery Time	t _{rr}			60	90	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = - 50 A, dI/dt = 100 A/μs		- 3	- 4.5	Α	
Reverse Recovery Charge				0.09	0.2	μС	

Notes:

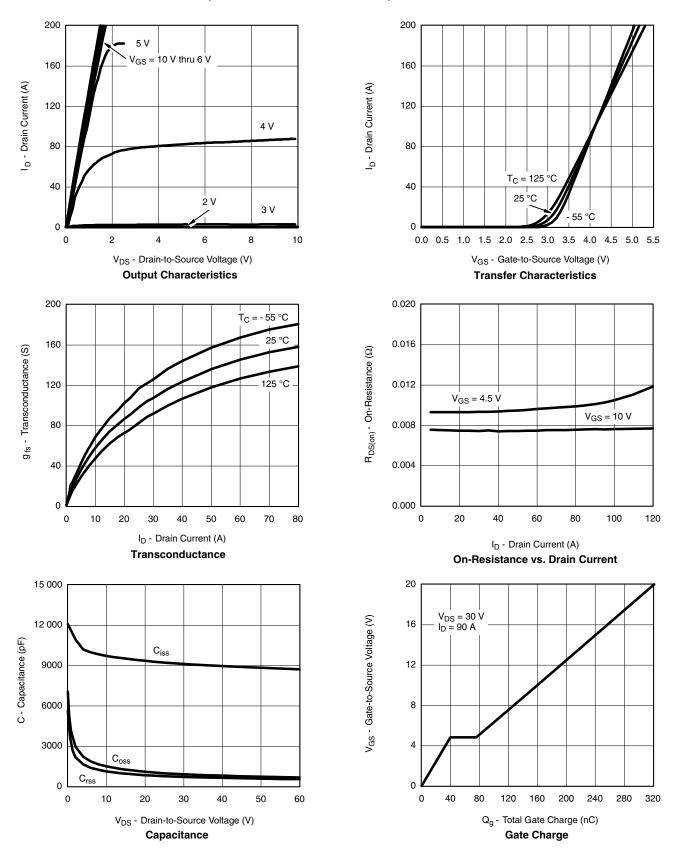
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





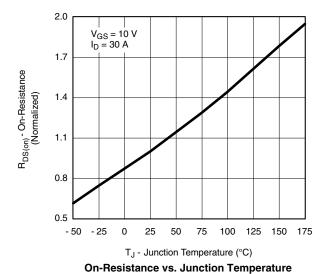
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

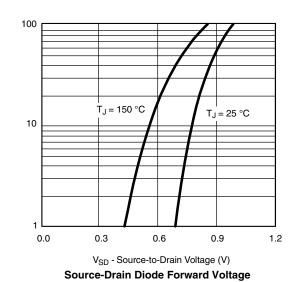


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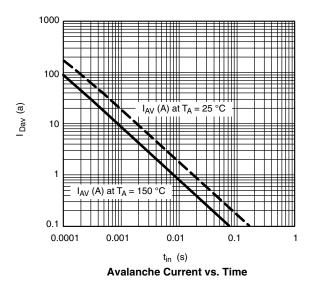
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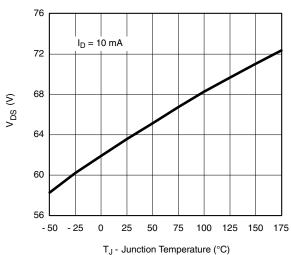
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





Is - Source Current (A)



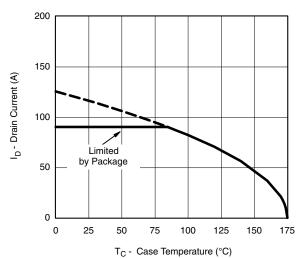


Drain Source Breakdown vs.
Junction Temperature

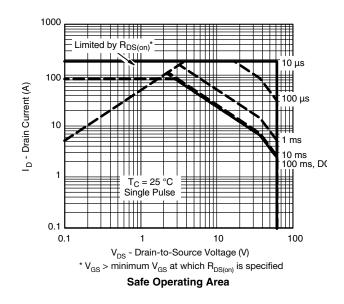


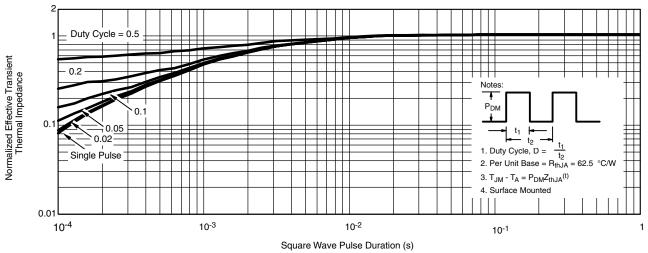


THERMAL RATINGS



Maximum Avalanche and Drain Current vs. Case Temperature





Normalized Thermal Transient Impedance, Junction-to-Case

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TO-220AB



	D2

	MILLIMETERS		INCHES	
DIM.	MIN.	MAX.	MIN.	MAX.
А	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
С	0.36	0.61	0.014	0.024
D	14.85	15.49	0.585	0.610
D2	12.19	12.70	0.480	0.500
Е	10.04	10.51	0.395	0.414
е	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	13.35	14.02	0.526	0.552
L(1)	3.32	3.82	0.131	0.150
ØΡ	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
ECN: T14-0413-Rev. P, 16-Jun-14 DWG: 5471				

Note

 $^{^{\}star}$ M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



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